## **TEFD4300**

**Vishay Semiconductors** 



DESCRIPTION

visible and near infrared radiation.

TEFD4300 is a silicon PIN photodiode with high radiant

sensitivity in clear, T-1 plastic package. It is sensitive to

# Silicon PIN Photodiode

### **FEATURES**

- Package type: leaded
- Package form: T-1
- Dimensions (in mm): Ø 3
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- · Fast response times
- Angle of half sensitivity:  $\phi = \pm 20^{\circ}$
- Package matched with IR emitter series VSLB3940, TSUS4300, and TSAL4400
- · Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### Note

Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

#### **APPLICATIONS**

- · High speed photo detector for data transmission
- Optical switches
- Counters and sorters
- Interrupters
- Encoders
- Position sensors

PRODUCT SUMMARY			
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ <sub>0.1</sub> (nm)
TEFD4300	17	± 20	350 to 1120

Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	CKAGING REMARKS P/		
TEFD4300	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1	

#### Note

MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	60	V	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	Pv	215	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	$t \le 3$ s, 2 mm from case	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	450	K/W	

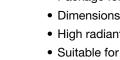
Document Number: 83471



RoHS

COMPLIANT

**GREEN** (5-2008)\*\*



# **TEFD4300**



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<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>		1		V
Breakdown voltage	I <sub>R</sub> = 100 μA, E = 0	V <sub>(BR)</sub>	60			V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>		0.15	3	nA
Diode capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	CD		3.3		pF
	V <sub>R</sub> = 5 V, f = 1 MHz, E = 0	CD		1.2		pF
Open circuit voltage	E <sub>e</sub> = 1 mW/cm <sup>2</sup> , l = 950 nm	Vo		350		mV
Temperature coefficient of Vo	E <sub>e</sub> = 1 mW/cm <sup>2</sup> , l = 950 nm	TK <sub>Vo</sub>		- 2.6		mV/K
Short circuit current	E <sub>e</sub> = 1 mW/cm <sup>2</sup> , l = 950 nm	l <sub>k</sub>		15		μA
Temperature coefficient of ${\sf I}_{\sf k}$	E <sub>e</sub> = 1 mW/cm <sup>2</sup> , l = 950 nm	TK <sub>lk</sub>		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2$ , I = 950 nm, V <sub>R</sub> = 5 V	I <sub>ra</sub>	9	17	27	μA
Angle of half sensitivity		φ		± 20		deg
Wavelength of peak sensitivity		λ <sub>p</sub>		950		nm
Range of spectral bandwidth		λ <sub>0.1</sub>	350		1120	nm
Rise time	$V_{R} = 10 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega, \text{ I} = 820 \text{ nm}$	t <sub>r</sub>		100		ns
Fall time	$V_{R} = 10 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega, \text{ I} = 820 \text{ nm}$	t <sub>f</sub>		100		ns

### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

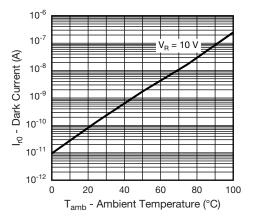


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

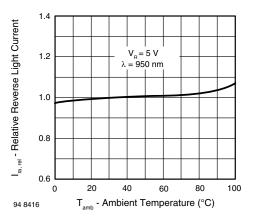


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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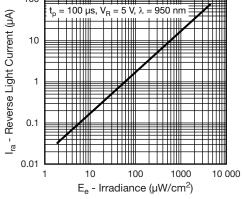


Fig. 3 - Reverse Light Current vs. Irradiance

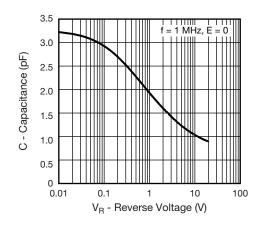


Fig. 4 - Diode Capacitance vs. Reverse Voltage

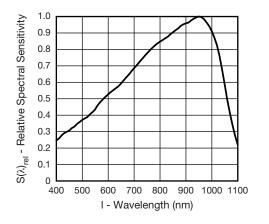


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

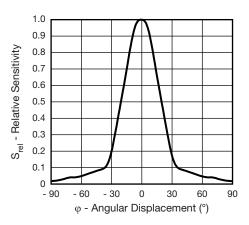


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

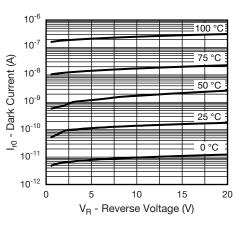


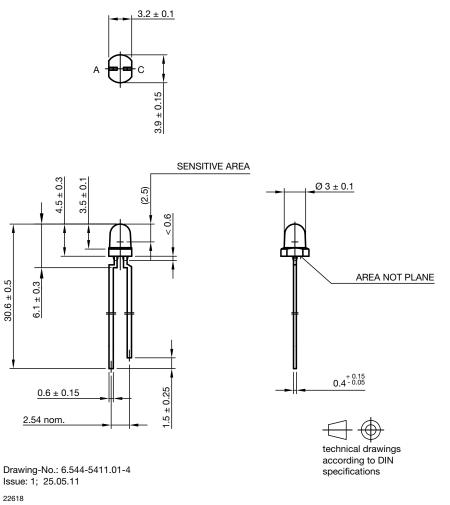
Fig. 7 - Dark Current vs. Reverse Voltage

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#### **PACKAGE DIMENSIONS** in millimeters





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